ASSP For Power Supply Applications

Switching Regulator Controller

MB3776A

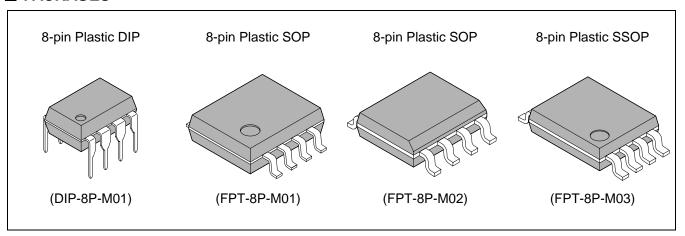
DESCRIPTION

MB3776A is a PWM system switching regulator controller. Because of its low operating supply voltage and power-down, the MB3776A is ideal for use in DC/DC converters for battery-powered portable equipment.

■ FEATURES

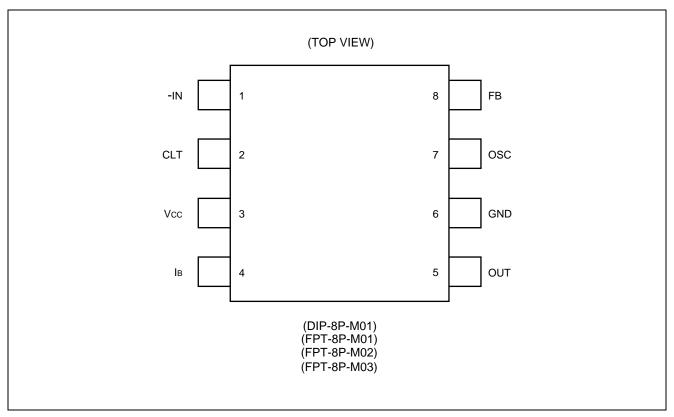
- Wide supply voltage range: (2 V to 15 V)
- Wide oscillation frequency range, high-frequency oscillation: (10 kHz to 500 kHz)
- · Push-pull output. Drive current set with external resistor
- Bulit-in idle period circuit
- Internally set error amplifier gain, few external components
- Bulit-in power-down function

■ PACKAGES

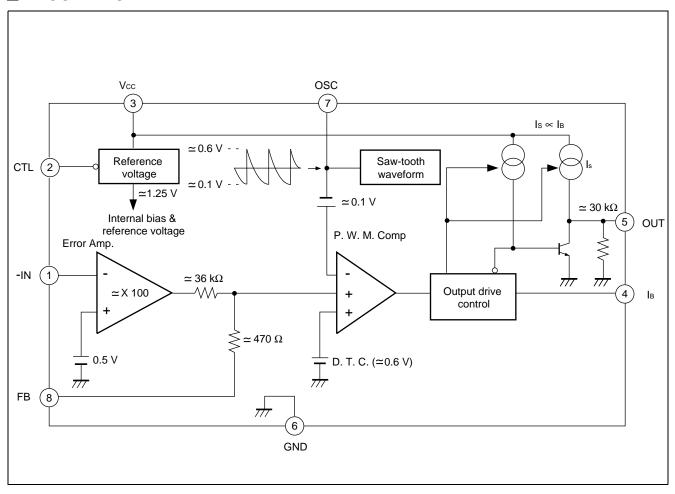




■ PIN ASSIGNMENT



■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

 $(Ta = +25^{\circ}C)$

Parameter	Symbol	Condition		Rating		Unit
raiailletei	Symbol	Condition	Condition		Max	Oilit
Power supply voltage	Vcc	_		_	16	V
Error amp. input voltage	Vı	_		-0.3	+10	V
Output source current	Isource	_		_	- 50	mA
Output sink current	Isink	_		_	50	mA
		Ta ≤ +25°C (DIP)		_	550	mW
Power dissipation	P₀	Ta ≤ +25°C (SOP)	EIAJ		*570	mW
rower dissipation	Fυ	la ≤ +25 C (50F)	JEDEC	_	*430	mW
		Ta < +25°C (SSOP)		_	*580	mW
Operating temperature	Тор	_		-30	+75	°C
Storage temperature	Tstg	_		- 55	+125	°C

^{*:} The packages are mounted on the epoxy board (10 cm \times 10 cm \times 1.5 mm)

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Dovernator	Cumbal		l lmit		
Parameter	Symbol	Min	Тур	Max	Unit
Power supply voltage	Vcc	2.0	_	15	V
Error amp. input voltage	Vı	-0.2	_	1.0	V
Output source current	Isource	-40	_	_	mA
Output sink current	Isink	_	_	40	mA
Phase compensation capacitor	СР	_	0.1	_	μF
Timing capacitor	Ст	100	1000	10000	pF
Timing resistor	R⊤	1.0	3.0	5.0	kΩ
Oscillator frequency	fosc	10	200	500	kHz
Operating temperature	Тор	-30	25	75	°C

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

1. Reference Section and Error Amp. Section

 $(Ta = +25^{\circ}C, Vcc = 3 V)$

Parameter	Symbol	Condition		Unit		
Farameter	Symbol	Condition	Min	Тур	Max	Ollit
Input threshold voltage	Vт	V _{FB} = 450 mV	487	507	527	mV
V⊤ input stability	V _{TdV1}	Vcc = 2.0 V to 6.0 V	- 5	_	5	mV
	V _{TdV2}	Vcc = 6.0 V to 15 V	- 5	_	5	mV
V⊤ temp. stability	V _{Td} T	Ta = -30 °C to +75 °C	-3	_	3	%
Input bias current	lв	V _{IN} = 0 V to 0.6 V	-1.0	-0.2	1.0	μΑ
Voltage gain	Av	_	70	100	145	V/V
Frequency band width	BW	$A_V = 0 dB$	_	6	_	MHz

2. Saw-tooth Waveform Oscillator Section

 $(Ta = +25^{\circ}C, Vcc = 3 V)$

Parameter	Symbol	Condition		Unit		
Farameter	Symbol	Condition	Min	Тур	Max	Unit
Oscillator frequency	fosc	$R_T = 3.0 \text{ k}\Omega$ $C_T = 1000 \text{ pF}$	160	200	240	kHz
Frequency input stability	f⊲∨	Vcc = 2.0 V to 15 V		±2		%
Frequency temp. stability	f _d т	Ta = -30 °C to $+75$ °C	_	±10	_	%

3. Under Lockout Protection

 $(Ta = +25^{\circ}C, Vcc = 3 V)$

Parameter	Symbol	Symbol Condition Value				
Farameter	Syllibol	Condition	Min	Тур	Max	Unit
Threshold voltage	V _{TH}	_	_	1.4	_	V

4. Dead-time Control Section

 $(Ta = +25^{\circ}C, Vcc = 3 V)$

Parameter	Symbol Condition		Value			Unit
i didiletei	Syllibol	Condition	Min	Тур	Max	Onit
Max duty cycle	t duty	$C_T = 1000 \text{ pF}$ $R_T = 3.0 \text{ k}\Omega$ $V_{FB} = 0.9 \text{ V}$	60	70	85	%

5. Output Section

 $(Ta = +25^{\circ}C, Vcc = 3 V)$

Parameter Symb		ol Condition		Value			
Farameter	Symbol	Condition	Min	Тур	Max	Unit	
Output source current	Isource	R _B = 820 Ω, V _O = 1 V	-40	-30	-20	mA	
Output sink current	Isink	R _B = 820 Ω, Vo = 0.3 V	30	60	_	mA	
High-level output voltage	Vон	$R_B = 820 \Omega$, $V_O = 7 V$ $I_O = -15 \text{ mA}$	5.5	6.0	_	V	
Output voltage	Vol	VcτL = Vcc, Io = 3 μA	_	0.1	0.2	V	

6. Control Section

 $(Ta = +25^{\circ}C, Vcc = 3 V)$

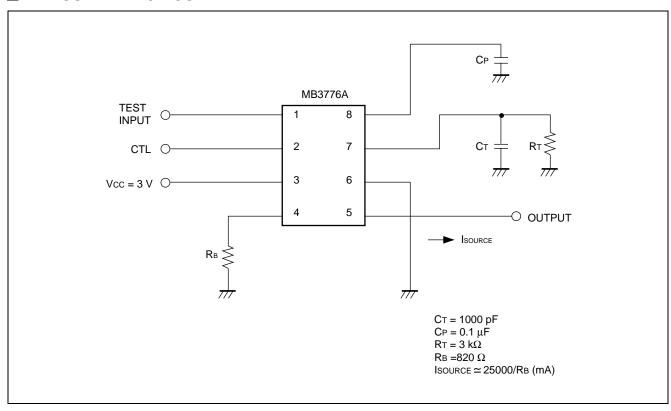
Parameter	Symbol Condition			Unit		
raiametei	Symbol	Condition	Min	Тур	Max	Onn
Input off condition	loff	_	-300		_	μΑ
Input on condition	Іон	_	_		-700	μΑ
Control terminal current	Ість	Vcc = 7 V, Vctl = 0 V	-1.3	-1	_	mA

7. All Device

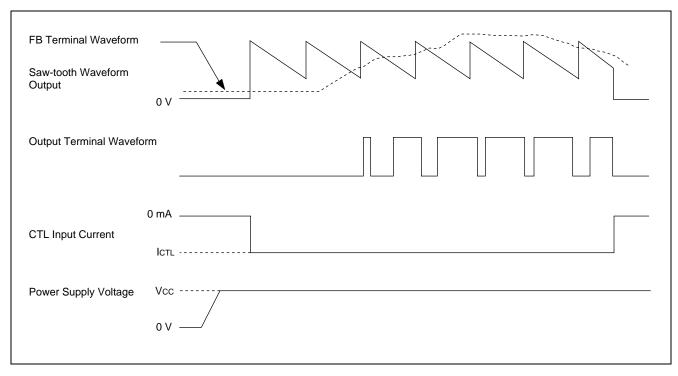
 $(Ta = +25^{\circ}C, Vcc = 3 V)$

Parameter	Symbol	Condition		Unit		
Farameter	Symbol	Min	Тур	Max		
Stand by current	Iccs	Vctl = Vcc or CTL terminal open	_	_	0.5	μΑ
Average supply current	Icc	$I_{CTL} = -700 \mu A$ $R_B = 820 \Omega$	_	4.5	8	mA

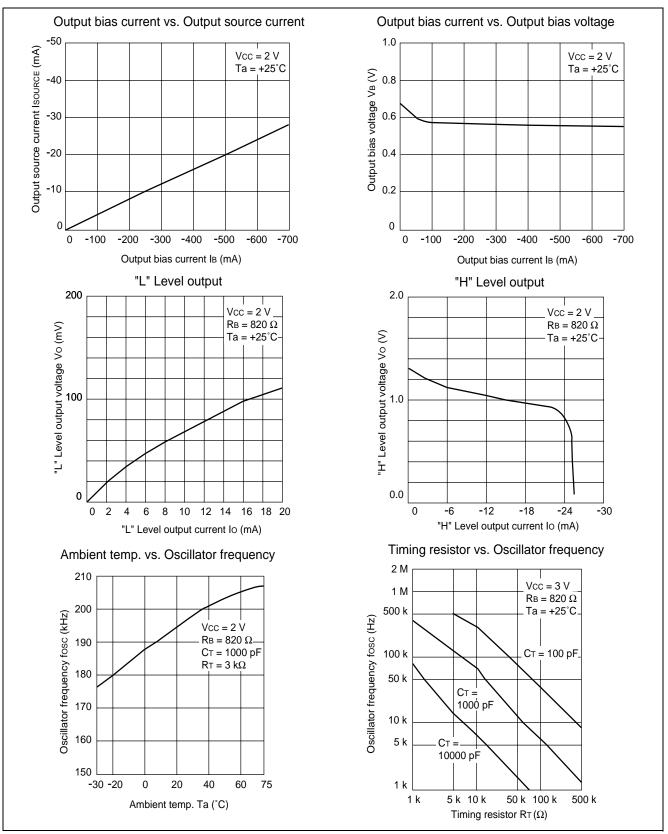
■ MEASURMENT CIRCUIT



■ DIAGRAM

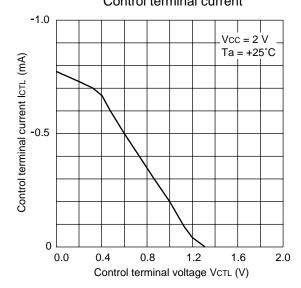


■ TYPICAL CHARACTERISTIC

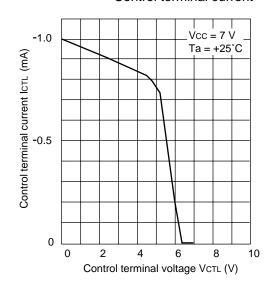


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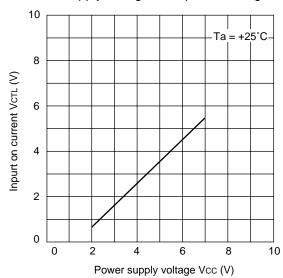
Control terminal voltage vs. Control terminal current



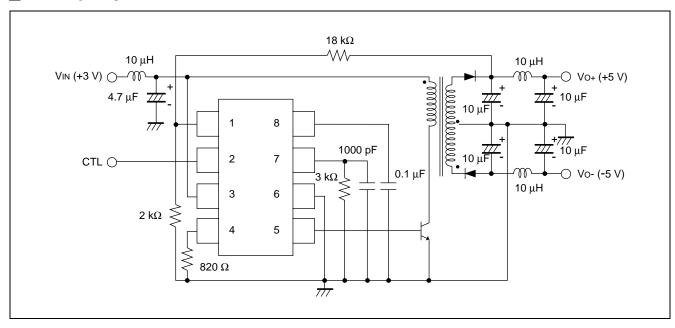
Control terminal voltage vs. Control terminal current



Power supply voltage vs. Input on voltage

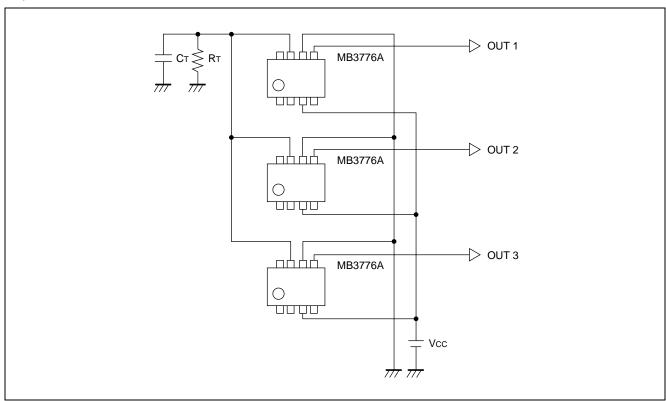


■ APPLICATION EXAMPLE



Synchronization

To synchronize MB3776A controllers, the OSC terminal of each IC is shared and the same specified capacitor and resistor used on a signal IC application is connected for self-excitation oscillation. The CTL terminal controls power on/off of each IC.



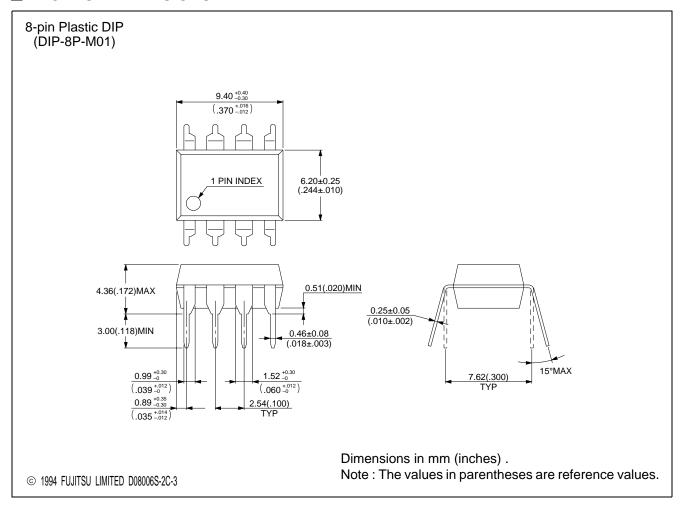
■ NOTES ON USE

- Take account of common impedance when designing the earth line on a printed wiring board.
- Take measures against static electricity.
 - For semiconductors, use antistatic or conductive containers.
 - When storing or carrying a printed circuit board after chip mounting, put it in a conductive bag or container.
 - The work table, tools and measuring instruments must be grounded.
 - The worker must put on a grounding device containing 250 k Ω to 1 M Ω resistors in series.
- Do not apply a negative voltage
 - Applying a negative voltage of -0.3 V or less to an LSI may generate a parasitic transistor, resulting in malfunction.

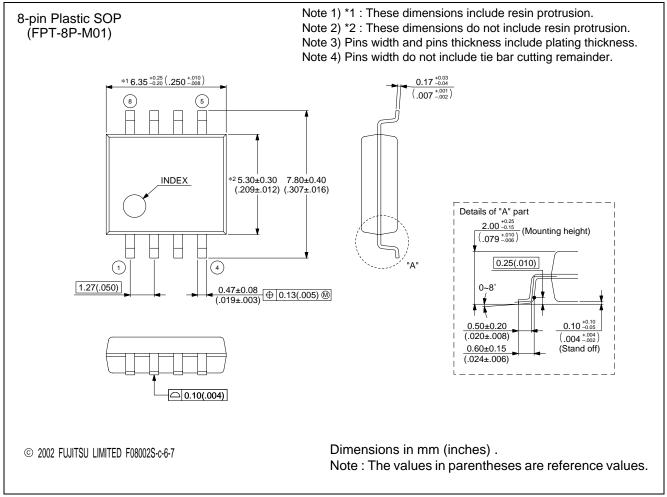
■ ORDERING INFORMATION

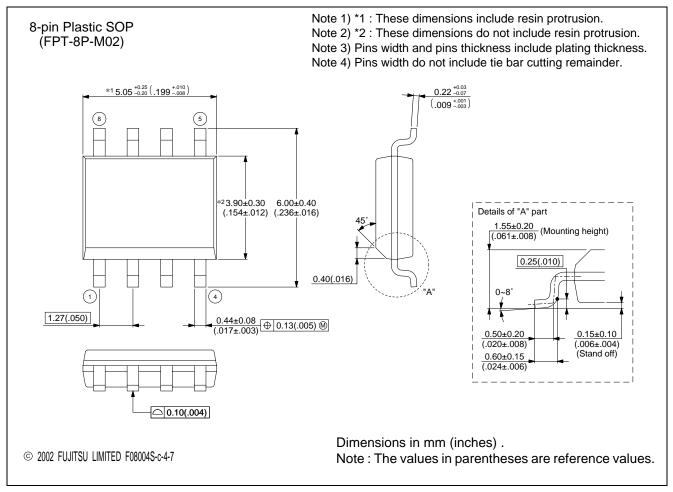
Part number	Package	Remarks
MB3776A-P	8-pin Plastic DIP (DIP-8P-M01)	
MB3776APF	8-pin Plastic SOP (FPT-8P-M01)	
MB3776APNF	8-pin Plastic SOP (FPT-8P-M02)	
MB3776APFV	8-pin Plastic SSOP (FPT-8P-M03)	

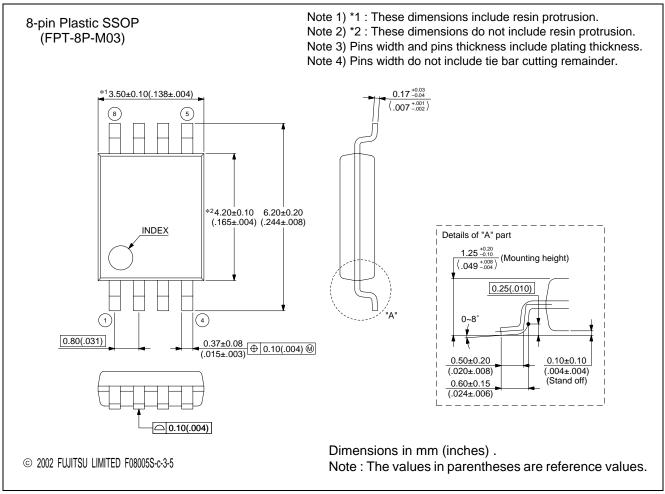
■ PACKAGE DIMENSIONS



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